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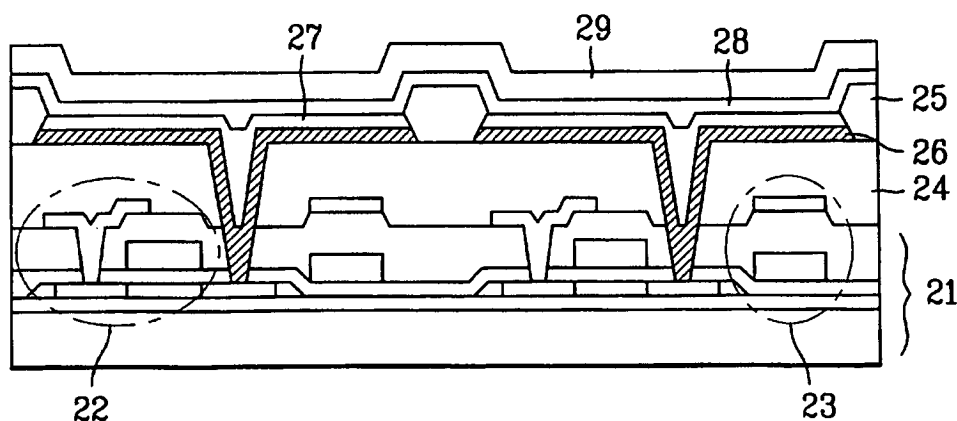
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(54) **Active Matrix Electro-Luminescent (Amel) display panel and method for fabricating the same**

(57) AMEL display panel including a substrate having a plurality of transistors, a planarizing layer on the substrate, an adhesive layer of silicon oxide, silicon nitride, or ITO on the planarizing layer, a first electrode on

the adhesive layer connected to the transistor electrically, an organic electroluminescence (EL) layer on the first electrode, and a second electrode on the organic EL layer.

FIG. 2





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EUROPEAN SEARCH REPORT

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The present search report has been drawn up for all claims			
Place of search Munich		Date of completion of the search 30 April 2008	Examiner Bernabé Prieto, A
CATEGORY OF CITED DOCUMENTS X : particularly relevant if taken alone Y : particularly relevant if combined with another document of the same category A : technological background O : non-written disclosure P : intermediate document T : theory or principle underlying the invention E : earlier patent document, but published on, or after the filing date D : document cited in the application L : document cited for other reasons & : member of the same patent family, corresponding document			

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**ANNEX TO THE EUROPEAN SEARCH REPORT
ON EUROPEAN PATENT APPLICATION NO.**

EP 03 01 2356

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The members are as contained in the European Patent Office EDP file on
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专利名称(译)	有源矩阵电致发光 (Amel) 显示面板及其制造方法		
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其他公开文献	EP1369936A2 EP1369936B1		
外部链接	Espacenet		

摘要(译)

AMEL显示面板，包括具有多个晶体管的基板，基板上的平坦化层，平坦化层上的氧化硅，氮化硅或ITO的粘合层，粘合层上的第一电极，电连接到晶体管，第一电极上的有机电致发光 (EL) 层和有机EL层上的第二电极。

FIG. 2

